

Main Application: Time-of-Flight measurements with heavy ions.

Ordering Information

- To Order: Add the appropriate letter prefix for the mounting desired. Example: ED-020-010-15 or TD-015-050-50. Unless specified otherwise, supplied in E Mount for up to 40.0 µm thickness; in T Mount for >40.0 µm thickness.
- NOTE: Alpha Suite Compatible Detectors: ULTRA-AS and Low-Background R Series detectors in B-mount are guaranteed compatible with the Alpha Suite products (DUO, MEGA, ARIA, ENSEMBLE). All other detectors require an approved special for compatibility and warranted specifications.

Active Area (mm²)	Maximum Thickness Variation	Depletion Depth† Depletion Depth 15 μm 25 μm Range 7-15 μm Range 15.1-25 μ		Depletion Depth† 40 μm Range 25.1-40 μm	Depletion Depth 50 μm Range 40.1-65 μm	Depletion Depth 75 μm Range 65.1-85 μm	Depletion Depth 100 μm Range 85.1-110 μm	
	(µm)	Model No.	Model No.	Model No.	Model No.	Model No.	Model No.	
10	±0.5	D-020-010-15						
50	±0.5	D-035-050-15	D-035-050-25	D-020-050-40	D-015-050-50	D-015-050-75	D-015-050-100	
150	±1.0		D-060-150-25	D-035-150-40	D-030-150-50	D-030-150-75	D-025-150-100	
300	±1.0		D-095-300-25	D-055-300-40	D-045-300-50	D-040-300-75	D-030-300-100	
450	±3.0		D-100-450-25	D-090-450-40	D-070-450-50	D-060-450-75	D-060-450-100	

* All standard totally depleted detectors are cut off-axis from the parent crystal at a specific angle that will minimize channeling. Larger areas available on special order. Other areas and depths available on special order.

** First three digits of Model No. indicate total system noise width measured with standard ORTEC electronics and 0.5-µs shaping time constants. Noise width is given for the smallest thickness (largest capacitance) in each range and specified nominal area. For high-capacitance units, performance depends on actual thickness and area.

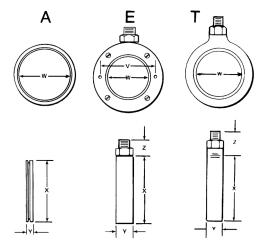
Mounting Arrangements

- A This is a "ring mount"; i.e., the silicon wafer is offered on its ring without output connectors. This infrequently used arrangement is available on special request. For 40 μm to 100 μm detectors.
- E This is a special type of transmission mount in which four screws can be carefully adjusted to avoid excessive pressure on particularly fragile silicon wafers. For up to 40.0 µm thick detectors.
- T Microdot connector on the side of the can (open back) for depletion depth >40.0 μm.

[†]E Mounts may be disassembled by removing screws. V dimension provides distance between mounting holes that are 1.7 mm in diameter and suitable for 0.080 screws.

Dimensions are given in millimeters.

	Detector		Type A Mount		Type E† Demountable Transmission				Type T Transmission Mount		
	Size (mm²)	W (Nominal)	Х	Y	Х	Y	Z	V	Х	Y	Z
	050	8.0	15.2	3.7	25.1	7.7	7.0	18.2	19.4	7.9	9.9
	150	13.8	22.0	3.7	31.9	7.7	7.0	25.0	26.1	7.9	9.9
ſ	300	19.5	27.1	3.7	37.1	7.7	7.0	30.1	31.6	7.9	9.9
ſ	450	23.9	30.5	3.7	40.2	7.7	7.0	33.3	34.8	7.9	9.9
	Tol.	±0.5	±0.3	±0.3	±0.5	±0.3	±0.3	±0.3	±0.3	±0.3	±0.3



Specifications subject to change 020821



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